12-Stage Binary Ripple Counter

The MC74AC4040 consists of 12 master-slave flip-flops. The output of each flip-flop feeds the next and the frequency at each output is half that of the preceding one. The state of the counter advances on the negative-going edge of the Clock input. Reset is asynchronous and active-high.

State changes of the Q outputs do not occur simultaneously because of internal ripple delays. Therefore, decoded output signals are subject to decoding spikes and may have to be gated with the Clock of the MC74AC4040 for some designs.

Features

- 140 MHz Typ. Clock
- Outputs Source/Sink 24 mA
- Operating Voltage Range: 2.0 to 6.0 V
- High Noise Immunity
- Pb-Free Packages are Available

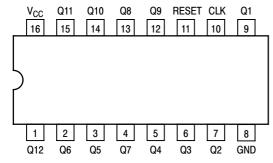


Figure 1. Pinout: 16-Lead Packages Conductors (Top View)

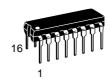
FUNCTION TABLE

Clock	Reset	Output State
	L	No Change
	L	Advance to next state
Х	Н	All Outputs are low



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PDIP-16 N SUFFIX CASE 648



SOIC-16 D SUFFIX CASE 751B



SOEIAJ-16 M SUFFIX CASE 966

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74AC4040N	PDIP-16	25 Units/Rail
MC74AC4040NG	PDIP-16 (Pb-Free)	25 Units/Rail
MC74AC4040D	SOIC-16	48 Units/Rail
MC74AC4040DG	SOIC-16 (Pb-Free)	48 Units/Rail
MC74AC4040DR2	SOIC-16	2500 Tape & Reel
MC74AC4040DR2G	SOIC-16 (Pb-Free)	2500 Tape & Reel
MC74AC4040M	SOEIAJ-16	50 Units/Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 4 of this data sheet.

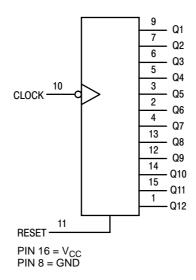


Figure 2. Logic Diagram

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V _{IN}	DC Input Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
V _{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
I _{IN}	DC Input Current, per Pin	±20	mA
I _{OUT}	DC Output Current, per Pin	±50	mA
I _{CC}	DC V _{CC} or GND Current per Output Pin	±50	mA
P _D	Power Dissipation in Still Air Plastic† SOIC Package†	750 500	mW
T _{stg}	Storage Temperature	-65 to +150	°C
T _L	Lead Temperature, 1 mm from Case for 10 seconds (Plastic DIP or SOIC Package)	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V _{IN} /V _{OUT}	Input Voltage, Output Voltage (Referenced to GND)	0	V _{CC}	_
T _A	Operating Temperature, All Package Types	-40	+85	°C
t _r /t _f	Input Rise/Fall Time $V_{CC} = 3.0 \text{ V}$ (Figure 1) $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 5.5 \text{ V}$	0 0 0	150 40 25	ns/V

[†]Derating: Plastic DIP: - 10mW/°C from 65°C to 125°C SOIC Package: -7.0 mW/°C from 65°C to 125°C

DC CHARACTERISTICS (unless otherwise specified)

Symbol	Parameter	Value	Unit	
I _{CC}	Maximum Quiescent Supply Voltage	80	μΑ	$V_{in} = V_{CC}$ or GND $V_{CC} = 5.5 \text{ V}, T_A = \text{Worst Case}$
I _{CC}	Maximum Quiescent Supply Current		μΑ	$V_{\text{in}} = V_{\text{CC}} \text{ or GND}$ $V_{\text{CC}} = 5.5 \text{ V}, T_{\text{A}} = 25^{\circ}\text{C}$

DC CHARACTERISTICS

			74	AC	74AC		
		V _{CC}	T _A = -	-25°C	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Symbol	Parameter	(V)	Тур	Typ Guaranteed Lim		Unit	Conditions
V _{IH}	Minimum High Level Input Voltage	3.0 4.5 5.5		2.1 3.15 3.85	2.1 3.15 3.85	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V
V _{IL}	Maximum Low Level Input Voltage	3.0 4.5 5.5	- - -	0.9 1.35 1.65	0.9 1.35 1.65	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V
V _{OH}	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I _{OUT} = -50 μA
		3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	V	$^*V_{IN} = V_{IL} \text{ or } V_{IH}$ -12 mA I_{OH} -24 mA -24 mA
V _{OL}	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	Ι _{ΟUT} = 50 μΑ
		3.0 4.5 5.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44	V	$^*V_{IN} = V_{IL} \text{ or } V_{IH}$ 12 mA I_{OL} 24 mA 24 mA
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	V _I = V _{CC} , GND
I _{OLD}	Minimum Dynamic Output Current†	5.5	-	-	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}		5.5	-	-	- 75	mA	V _{OHD} = 3.85 V Min

 $^{^{\}star}\text{All}$ outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms - See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

			74AC		74	AC			
		V _{CC} *		T _A = +25°C C _L = 50 pF					
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Unit	Fig. No.
f _{max}	Maximum Clock Frequency	3.3 5.0	110 130	120 140	-	100 120	-	MHz	-
n _{CP} to Q1	Propagation Delay n _{CP} to Q1	3.3 5.0	2.0 2.0	-	11 8.0	2.0 2.0	14 10	ns	-
Q _n to Q _n +1	Propagation Delay Q _n to Q _n +1	3.3 5.0	0 0		5.5 3.5	0 0	6.5 4.5	ns	-
MR to Q t _{HL}	Propagation Delay MR to Q	3.3 5.0	3.0 3.0		12 10	3.0 3.0	15 12	ns	-
t _{rec} n _{CP} to MR	Recovery Time	3.3 5.0	0 0	-2.5 -1.5	-	0 0	-	ns	-
t _w n _{CP}	Minimum Pulse Width Clock Pin	3.3 5.0	4.0 3.0	3.5 2.5	_ _	4.5 3.5		ns	-
t _w MR	Minimum Pulse Width Master Reset	3.3 3.0	4.0 3.0	3.5 2.5	- -	4.5 3.5	-	ns	_

^{*}Voltage Range 3.3 V is 3.3 V ± 0.3 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	50	pF	V _{CC} = 5.0 V

MARKING DIAGRAMS

PDIP-16

 SOIC-16

AC4040G AWLYWW SOEIAJ-16

74AC4040 ALYW

A = Assembly Location

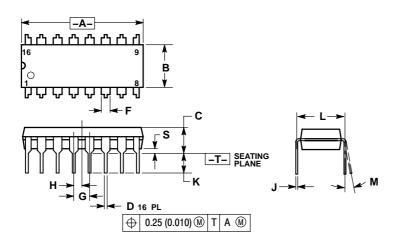
WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

G = Pb-Free Package

^{*}Voltage Range 5.0 V is 5.0 V ±0.5 V.

PACKAGE DIMENSIONS

PDIP-16 CASE 648-08 **ISSUE T**



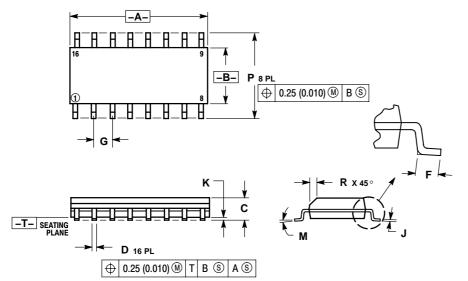
STYLE 2: PIN 1. 2. STYLE 1: PIN 1. COMMON DRAIN CATHODE CATHODE CATHODE COMMON DRAIN COMMON DRAIN 3. 4. 5. 3 CATHODE COMMON DRAIN CATHODE CATHODE CATHODE COMMON DRAIN 6. 7. 6. 7. 8. 9. 10. 11. COMMON DRAIN COMMON DRAIN COMMON DRAIN GATE SOURCE CATHODE ANODE ANODE 9. 10. 11. ANODE GATE 12. SOURCE 13. GATE 12. ANODE ANODE 13. 14. ANODE 14. SOURCE 15. ANODE 15. GATE 16. SOURCE

NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEADS
 WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54 BSC	
Н	0.050	BSC	1.27	BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
М	0°	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

SOIC CASE 751B-05 **ISSUE J**



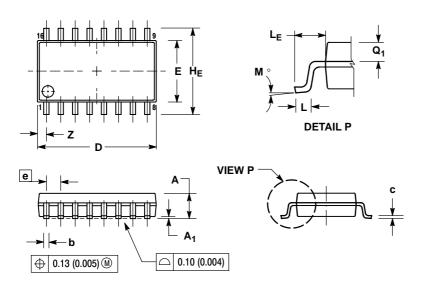
16. ANODE

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL
 IN EXCESS OF THE D DIMENSION AT
 MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
P	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

PACKAGE DIMENSIONS

SOEIAJ-16 CASE 966-01 **ISSUE A**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 - CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006)
- TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
 THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION.
 DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
е	1.27 BSC		0.050	BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q_1	0.70	0.90	0.028	0.035
Z		0.78		0.031

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